### Silicon N-Channel MOS FET

# **HITACHI**

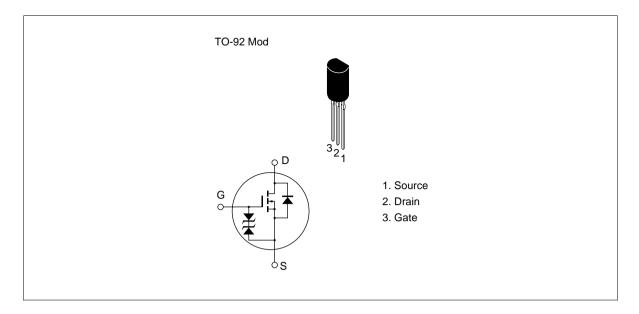
#### **Application**

High speed power switching

#### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

#### **Outline**





## **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

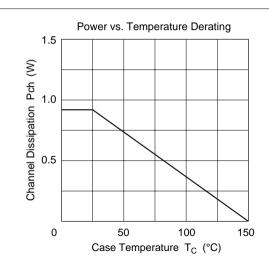
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	1.5	A
Drain peak current	I <sub>D(pulse)</sub> *1	4.5	А
Body to drain diode reverse drain current	I <sub>DR</sub>	1.5	A
Channel dissipation	Pch	900	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

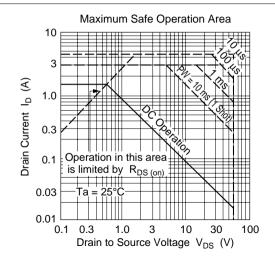
Note: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

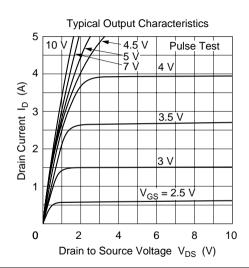
## **Electrical Characteristics** (Ta = 25°C)

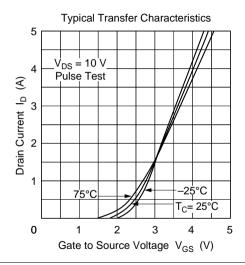
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	100	μΑ	$V_{DS} = 50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{\text{GS(off)}}$	1.0	_	2.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{\scriptscriptstyle DS(off)}$	_	0.3	0.4	Ω	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}^{*1}$
			0.4	0.55	Ω	$I_D = 1 \text{ A}, V_{GS} = 4 \text{ V}^{*1}$
Forward transfer admittance	yfs	0.9	1.5	_	S	I <sub>D</sub> = 1 A, V <sub>DS</sub> = 10 V *1
Input capacitance	Ciss	_	140	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	70	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	20	_	pF	
Turn-on delay time	$t_{d(on)}$	_	3	_	ns	$I_D = 1 A, V_{GS} = 10 V,$
Rise time	t <sub>r</sub>	_	12	_	ns	$R_L = 30 \Omega$
Turn-off delay time	$t_{\text{d(off)}}$	_	50	_	ns	
Fall time	t <sub>f</sub>	_	30	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	0.9	_	V	I <sub>F</sub> = 1.5 A, V <sub>GS</sub> = 0
Body to drain diode reverse recovery time	t <sub>rr</sub>		45		ns	$I_F = 1.5 \text{ A}, V_{GS} = 0,$ $di_F/dt = 50 \text{ A}/\mu\text{s}$

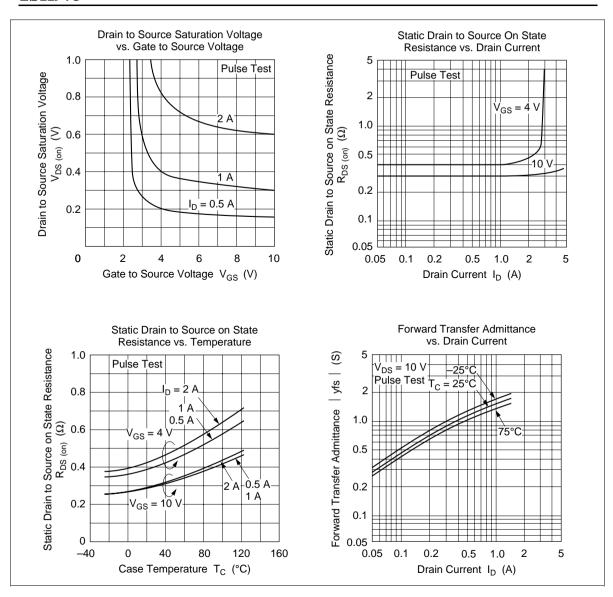
Note: 1. Pulse test

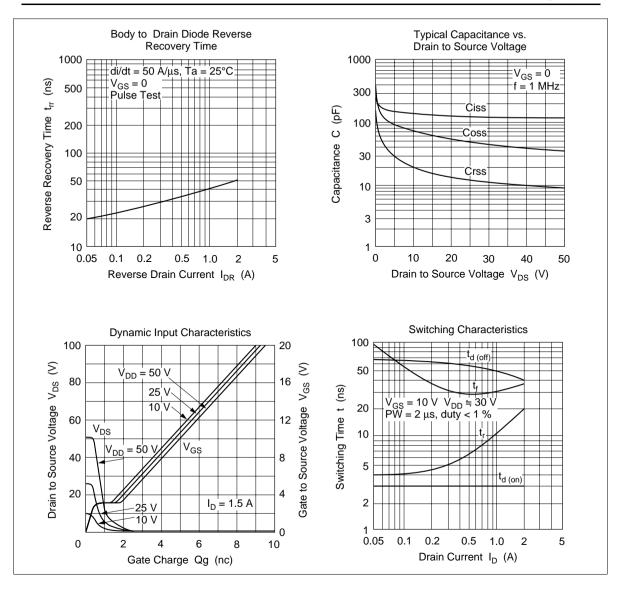


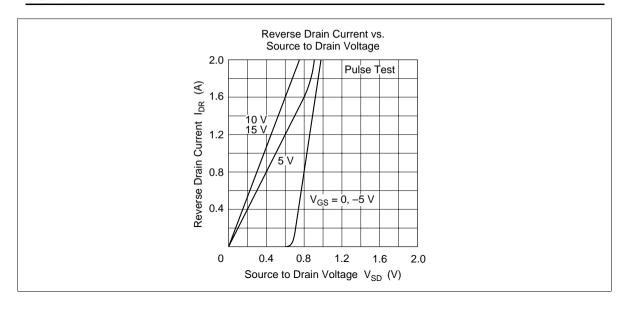




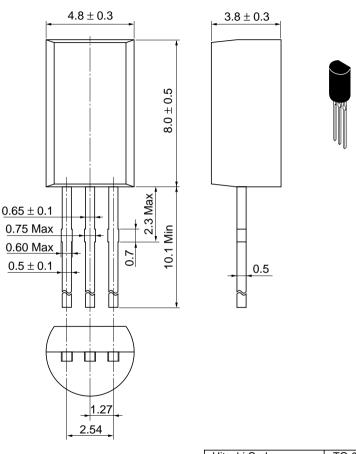








Unit: mm



Hitachi Code	TO-92 Mod
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.35 g

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